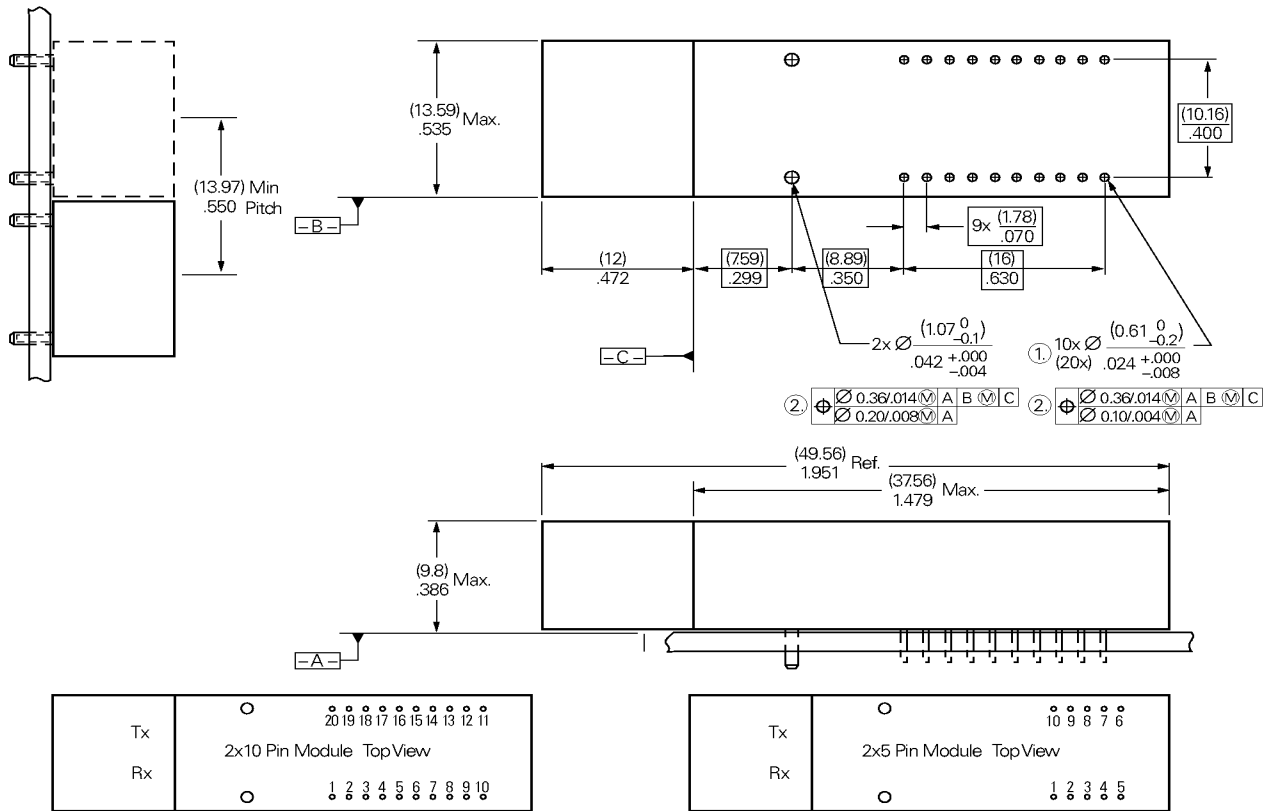


V23818-K305-V10

Small Form Factor Multimode 850 nm 1.3 Gigabit Ethernet 2x5 Transceiver with VF-45 (Volition™) Connector

Preliminary

Dimensions in (mm) inches



- ① Toleranced to accommodate round or rectangular leads.
- ② All 22 pins and posts are to be treated as a single pattern.

FEATURES

- **Small Form Factor transceiver unit for VF-45 (Volition™) connector**
- **RJ-45 style connector system**
- **Half the size of SC Duplex 1x9 transceiver**
- **Fully compliant with all major standards**
- **SONET OC3**
- **Single power supply (+3.3 V)**
- **Extremely low power consumption < 0.7 W**
- **PECL differential inputs and outputs**
- **System optimized for 62.5/50 μm graded index fiber**
- **Multisource footprint**
- **Small footprint for high channel density**
- **UL-94 V-0 certified**
- **ESD Class 2 per MIL-STD 883 Method 3015**
- **Compliant with FCC (Class B) and EN 55022**
- **For distances of up to 550 m**

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Absolute Maximum Ratings

Exceeding any one of these values may destroy the device immediately.

Package Power Dissipation ⁽¹⁾	1.5 W
Data Input Levels (PECL)	V _{CC} +0.5 V
Differential Data Input Voltage	+3 V
Operating Case Temperature	0°C to 70°C
Storage Ambient Temperature	-40°C to 85°C
Soldering Conditions, Temp/Time	
(MIL-STD 883C, Method 2003)	250°C/5.5s

Note

1. For V_{CC}-V_{EE} (min., max.). 50% duty cycle. The supply current does not include the load drive current of the receiver output. Add max. 45 mA for the three outputs. Load is 50 Ω to V_{CC}-2 V.

Volition™ is a trademark of 3M.

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Receiver Electro-Optical Characteristics

Receiver	Symbol	Min.	Typ.	Max.	Units
Sensitivity (Average Power) ⁽¹⁾	P _{IN}		-19	-17	dBm
Saturation (Average Power)	P _{SAT}	0			
Signal Detect Assert Level ⁽²⁾	P _{SDA}		-24	-20	
Signal Detect Deassert Level ⁽³⁾	P _{SDD}	-30	-27		
Signal Detect Hysteresis	P _{SDA} -P _{SDD}		3		dB
Signal Detect Assert Time	t _{ASS}			100	μs
Signal Detect Deassert Time	t _{DAS}			350	
Output Low Voltage ⁽⁴⁾	V _{OL} -V _{CC}	-1950		-1600	mV
Output High Voltage ⁽⁴⁾	V _{OH} -V _{CC}	-1025		-720	
Output Data Rise/Fall Time, 20%-80%	t _R , t _F			375	ps
Return Loss of Receiver	A _{RL}	12			dB

Notes

- Minimum average optical power at which the BER is less than 1 x 10E-12. Measured with a 2⁷-1 NRZ PRBS and ER=9 dB.
- An increase in optical power above the specified level will cause the SIGNAL DETECT output to switch from a Low state to a High state.
- A decrease in optical power below the specified level will cause the SIGNAL DETECT to change from a High state to a Low state.
- PECL compatible. Load is 50 Ω into V_{CC}-2V. Measured under DC conditions. For dynamic measurements a tolerance of 50 mV should be added.

Regulatory Compliance

Feature	Standard	Comments
Electrostatic Discharge (ESD) to the Electrical Pins	MIL-STD 883C Method 3015.4	Class 1 (>1000 V)
Immunity: Electrostatic Discharge (ESD) to the Duplex SC Receptacle	EN 61000-4-2 IEC 1000-4-2	Discharges of ±15kV with an air discharge probe on the receptacle cause no damage.
Immunity: Radio Frequency Electromagnetic Field	EN 61000-4-3 IEC 1000-4-3	With a field strength of 10 V/m rms, noise frequency ranges from 10 MHz to 1 GHz. No effect on transceiver performance between the specification limits.
Emission: Electromagnetic Interference (EMI)	FCC Class B EN 55022 Class B CISPR 22	Noise frequency range: 30 MHz to 1 GHz

LASER SAFETY

This multimode Gigabit Ethernet transceiver is a Class 1 laser product. It complies with IEC 825-1 and FDA 21 CFR 1040.10 and 1040.11. The transceiver must be operated under recommended operating conditions. Because the transceiver design is designed to be inherently eye safe, it does not require open fiber control thus eliminating complex electronics or mechanics.

Caution

The use of optical instruments with this product will increase eye hazard!

General Restrictions

Classification is valid only if the module is operated within the specified temperature and voltage limits. The system using the module must provide power supply protection that guarantees that the system power source will cease to provide power if the maximum recommended operation limit or more is detected on the +3.3 V at the power source. The case temperature of the module must be in the temperature range given in the recommended operating limits. These limits guarantee the laser safety.

Usage Restrictions

The optical ports of the modules shall be terminated with an optical connector or with a dust plug.

Note

Failure to adhere to the above restrictions could result in a modification that is considered an act of "manufacturing," and will require, under law, recertification of the modified product with the U.S. Food and Drug Administration (ref. 21 CFR 1040.10 (i)).

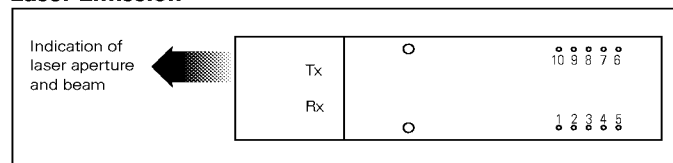
Laser Data

Wavelength	850 nm
Total output power (as defined by IEC: 50 mm aperture at 10 cm distance)	<400 μW
Total output power (as defined by FDA: 7 mm aperture at 20 cm distance)	<70 μW
Beam divergence	12°

Required Labels

FDA	IEC
Complies with 21 CFR 1040.10 and 1040.11	Class 1 Laser Product

Laser Emission

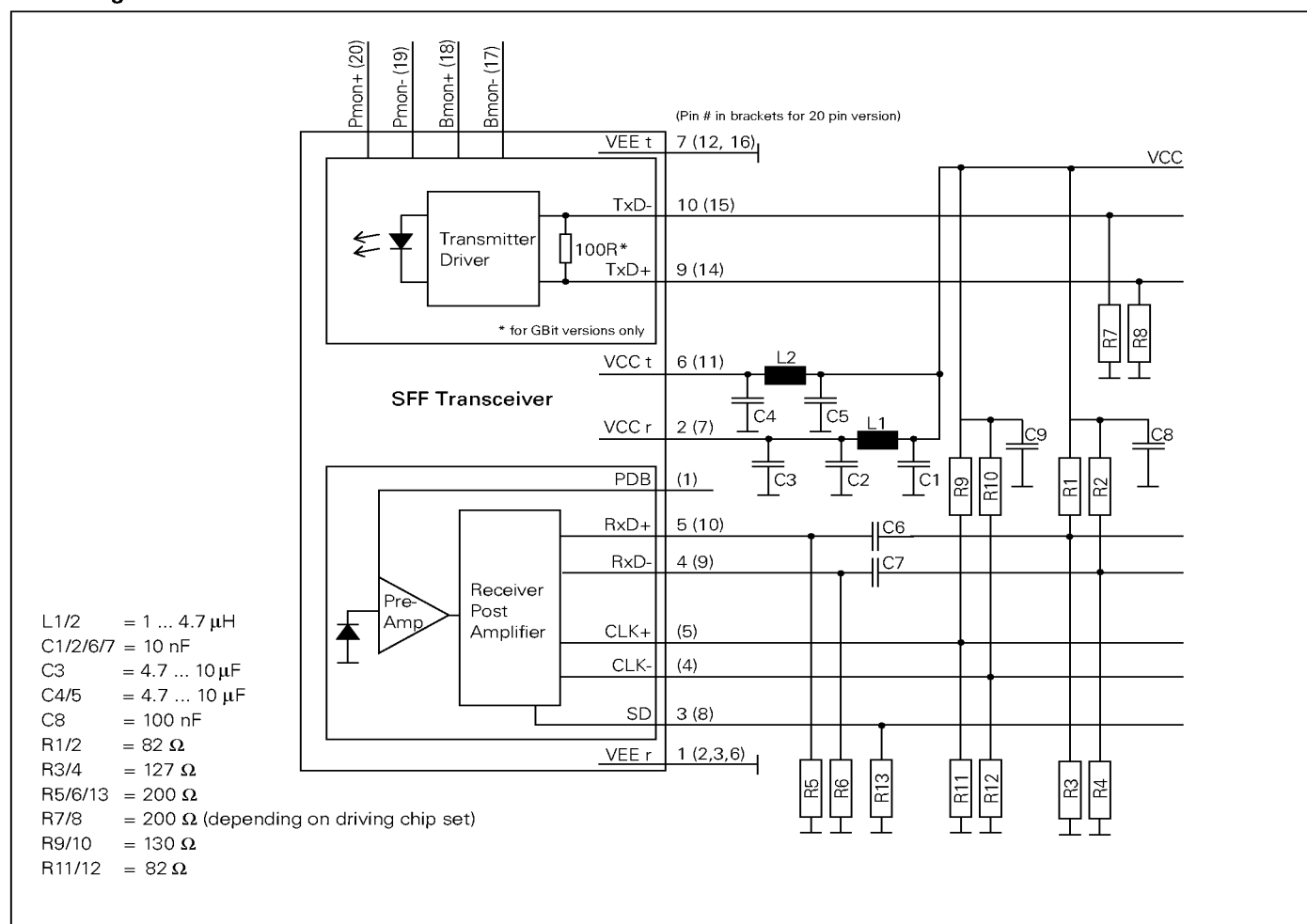


Pin Description

Pin Name	Level/Logic	Pin#	Description
V _{EEr}	Receiver Signal Ground	N/A	1
V _{CCr}	Receiver Power Supply	N/A	2
SD	Signal Detect	PECL	3 Normal Operation: Logic "1" Output Fault Condition: Logic "0" Output
RD-	Received Data Out Bar	PECL	4 No internal terminations will be provided.
RD+	Received Data Out	PECL	5 No internal terminations will be provided.
V _{CCt}		N/A	6 Transmitter Power Supply
V _{EEt}		N/A	7 Transmitter Signal Ground
TDis		TTL	8 Optional use for Laser based products only.
TD+		PECL	9 Transmitter Data In
TD-		PECL	10 Transmitter Data In Bar See TD+ pin for terminations
MS	MS	N/A	MS Mounting Studs The mounting studs are provided for transceiver mechanical attachment to the circuit board. They also provide an optional connection of the transceiver to the equipment chassis ground. The holes in the circuit board must be tied to chassis ground.

APPLICATION NOTE

850nm Gigabit Ethernet 2x5 Transceiver



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